Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-466-1540

1	nclosure Material:
	Glass and metal
(Overall Length:
C	0.260 inches
٦	Ferminal Length:
1	.500 inches
(Overall Diameter:
C	0.370 inches
I	nternal Configuration:
J	lunction contact
N	Nounting Method:
٦	erminal
٦	Ferminal Circle Diameter:
C	0.200 inches
F	Features Provided:
ŀ	termetically sealed case
Ś	Semiconductor Material:
S	Silicon
١	/oltage Rating In Volts Per Characteristic:
5	50.0 breakover voltage, dc
(Current Rating Per Characteristic:
1	.60 amperes source cutoff current preset
ſ	Naximum Operating Tempurature Per Measurement Point:
1	00.0 degrees celsius case
Ś	Special Features:
J	lunction pattern arrangement: pnpn
٦	Terminal Type And Quantity:
3	uninsulated wire lead
Ś	Shelf Life:
٢	I∕a
ι	Jnit Of Measure:
- [- Demilitarization:
	/es - demil/mli
	iig:
1	A110a0